# Investigation of TPC prototype using 266nm UV laser tracks for CEPC

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AFAD 2021, March, 17, 2021

## Outline

## Motivation

## TPC module and readout

## TPC prototype R&D

## Summary

## Motivation

projection steetons and m

end-plate

### TPC critical R&D for Z

- TPC can provide large-volume high-precision 3D track measurement with stringent material budget
- In order to achieve the high spatial resolution (<100um in all drift length), small pads (e.g.1mm×6mm) are needed, resulting ~1million channels of readout electronics
- Need low power consumption readout electronics working at continuous mode
- Need effectively reduce ions

| 5) | Momentum resolution (B=3.5T) | $\delta(^{1}/p_{t} \approx 10^{-4}/GeV/c)$                               |  |
|----|------------------------------|--|--|
|    | $\delta_{point}$ in $r\Phi$  | <100 µm  |  |
|    | $\delta_{point}$ in $rz$     | 0.4-1.4 mm   |  |
|    | Inner radius                 | 329 mm   |  |
|    | Outer radius                 | 1800 mm  |  |
|    | Drift length                 | 2350 mm  |  |
|    | TPC material budget          | $\approx 0.05 X_0$ incl. field cage $< 0.25 X_0$ for readout endcap      |  |
|    | Pad pitch/no. padrows        | $\approx 1 \text{ mm} \times (4 \sim 10 \text{ mm}) / \approx 200$       |  |
|    | 2-hit resolution             | $\approx 2 \text{ mm}$   |  |
|    | Efficiency                   | >97% for TPC only ( $p_t > 1GeV$ )<br>>99% all tracking ( $p_t > 1GeV$ ) |  |

#### **CEPC High Luminosity Parameters after CDR**

|   | tt           | Higgs        | W            | 2           | <i>.</i>     |
|---|--------------|--------------|--------------|-------------|--------------|
| Number of IPs                             | 2            | 2            | 2            |             | 2            |
| Energy (GeV)                              | 180          | 120          | 80           | 45          | .5           |
| Circumference (km)                        | 100          | 100          | 100          | 100         |              |
| SR loss/turn (GeV)                        | 8.53         | 1.73         | 0.33         | 0.036       |              |
| Half crossing angle (mrad)                | 16.5         | 16.5         | 16.5         | 16          | 5.5          |
| Piwinski angle                            | 1.16         | 4.87         | 9.12         | 24          | .9           |
| N <sub>e</sub> /bunch (10 <sup>10</sup> ) | 20.1         | 16.3         | 11.6         | 15          | .2           |
| Bunch number (bunch spacing)              | 37 (4.45µs)  | 214 (0.7us)  | 1588 (0.2µs) | 3816 (86ns) | 11498 (26ns) |
| Beam current (mA)                         | 3.5          | 16.8         | 88.5         | 278.8       | 839.9        |
| SR power /beam (MW)                       | 30           | 30           | 30           | 10          | 30           |
| Bending radius (km)                       | 10.7         | 10.7         | 10.7         | 10          | .7           |
| Phase advance of arc cell                 | 90°/90°      | 90°/90°      | 90°/90°      | 60°/60°     |              |
| Momentum compaction (10-5)                | 0.73         | 0.73         | 0.73         | 1.48        |              |
| $\beta_{IP} x/y (m)$                      | 1.0/0.0027   | 0.33/0.001   | 0.33/0.001   | 0.15/0.001  |              |
| Emittance x/y (nm)                        | 1.45/0.0047  | 0.68/0.0014  | 0.28/0.00084 | 0.27/0      | .00135       |
| Transverse $\sigma_{IP}$ (um)             | 37.9/0.11    | 15.0/0.037   | 9.6/0.029    | 6.36/       | 0.037        |
| $\xi_x/\xi_y/IP$                          | 0.076/0.106  | 0.018/0.115  | 0.014/0.13   | 0.0046      | /0.131       |
| $V_{RF}(GV)$                              | 9.52         | 2.27         | 0.47         | 0.          | 1            |
| f <sub>RF</sub> (MHz) (harmonic)          | 650 (216816) | 650 (216816) | 650 (216816) | 650 (2      | 16816)       |
| Nature bunch length $\sigma_z$ (mm)       | 2.23         | 2.25         | 2.4          | 2.1         | 75           |
| Bunch length $\sigma_z$ (mm)              | 2.66         | 4.42         | 5.3          | 9.          | 6            |
| HOM power/cavity (kw)                     | 0.45 (5cell) | 0.48 (2cell) | 0.79 (2cell) | 2.0 (2cell) | 3.02 (1cell) |
| Energy spread (%)                         | 0.17         | 0.19         | 0.11         | 0.          | 12           |
| Energy acceptance requirement (DA) (%)    | 2.0          | 1.7          | 1.2          | 1.          | 3            |
| Energy acceptance by RF (%)               | 2.01         | 2.5          | 1.02         | 1.4         | 48           |
| Lifetime (nour)                           | 0.59         | 0.35         | 1.3          | 1.7         | 1.1          |
| I /ID (1034am-2e-1)                       | 0.5          | 5.0          | 18.7         | 35.0        | 105.5        |

## TPC module R&D

## TPC detector module@ IHEP

#### **Study with GEM-MM module**

- New assembled module
- Active area: 100mm × 100mm
- **X-tube ray and 55Fe source**
- Bulk-Micromegas assembled from Saclay
- Standard GEM from CERN
- Avalanche gap of MM:128μm
- Transfer gap: 2mm
- Drift length:2mm~200mm
- pA current meter: Keithley 6517B
- Current recording: Auto-record interface by LabView
- **Standard Mesh: 400LPI**
- High mesh: 508 LPI
- Pixel option for the consideration in 2020

| DOI: 10.1088/1748-0221/12/04/P0401 JINST, 2017.4 |
|--|
| DOI: 10.1088/1674-1137/41/5/056003, CPC,2016.11  |
| DOI: 10.7498/aps.66.072901Acta Phys. Sin. 2017,7 |
| DOI: 10.1142/S2010194518601217 (SCI) 2018        |
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| DOI: 10.1007/978-981-13-1316-5_20 (SCI) 2018     |





GEM-MM detector cathode

## **GEM+MM**

#### Micronegas + GEM detector module @IHEP



IBF×Gain ratio can meet less than 2 at the lower gain under two mixture gases
 Lower gain and lower IBF ratio

## Space charge effect at the different gain



lons per UV light pulse (fC/cm^2)

- **Preliminary estimation of the high luminosity Z**
- There are more safe factor when the detector will run at the lower gain (eg.2000-3000)

## Specifics of ASIC using 65nm

- In order to reduce the power consumption:
  - Using more advanced 65 nm CMOS process favoring digital logics
  - Reducing analog circuits:
    - CR-(RC)<sup>n</sup>  $\rightarrow$  CR-RC, moving high order shaping to digital domain
    - ADC structure : pipeline  $\rightarrow$  SAR (Successive Approximation Register)
- So far only the AFE and the ADC parts have been implemented



- AFE + waveform sampling ADC + direct output
- Process: TSMC 65nm LP
- Power supply: 1.2V

|   | AFE(Analog Front-End)          |               |  |  |  |
|---|--------------------------------|---------------|--|--|--|
|   | Signal Polarity                | Negative      |  |  |  |
|   | Detector Capacitance           | 5-20 pF       |  |  |  |
|   | Shaper                         | CR-RC         |  |  |  |
|   | Shaping Time                   | 160 ns        |  |  |  |
| S | ENC (Equivalent Noise Charge)  | <500 e @ 10pF |  |  |  |
|   | Dynamic Range                  | 120 fC max.   |  |  |  |
|   | Gain                           | 10-40  mV/fC  |  |  |  |
|   | INL (Integrated Non-Linearity) | <1%           |  |  |  |
|   | Crosstalk                      | <1%           |  |  |  |
|   | Power Consumption (AFE)        | <2.5 mW/ch    |  |  |  |
|   |                                |               |  |  |  |

| SAR-ADC                 |                          |  |  |  |
|-------------------------|--------------------------|--|--|--|
| Input Range             | -0.6 $V\sim 0.6~V$ diff. |  |  |  |
| Resolution              | 10 bit                   |  |  |  |
| Sampling Rate           | 40 MS/s                  |  |  |  |
| DNL                     | <0.6 LSB                 |  |  |  |
| INL                     | <0.6 LSB                 |  |  |  |
| SFDR @ 2MHz, 40MSPS     | 68 dBc                   |  |  |  |
| SINAD                   | 57 dB                    |  |  |  |
| ENOB                    | >9.2 bit @ 2MHz          |  |  |  |
| Power Consumption (ADC) | <2.5 mW/ch               |  |  |  |

## Tests of the ASIC chip

# Topur Analog Front-End Bias SAR ADC

- A 16 channel low power readout ASIC for TPC readout have been developed
- The power consumption is 2.33 mW/channel:
  - P<sub>AFE</sub>=1.43 mW/channel
  - $P_{ADC} = 0.9 \text{ mW/channel} @ 40 \text{MS/s}$
- ENC = 852 e @ Cin=2 pF, gain=10 mV/fC and can be reduced to 474 e using digital trapezoidal filter
- The ASIC have been taped out in
  - November, 2019 and is being evaluated

LVDS driver

#### Layout of ASIC chip

• Transient outputs











Gain = 4.4 LSB/fC = 4.4 x 2.34 mV/fC = 10.3 mV/fC

#### Test of the signals \_9-

## TPC prototype R&D

## **TPC Prototype sketch**

- Main parameters
  - □ Same test parameters in CEPC
    - Drift field=200V/cm
    - Relative gain: ≥2000
    - Readout pad(anode) is designed to 0V (Ground) nreliminary
    - TPC detector system: Fieldcage+
      Pads readout
    - Working mixture gas:
      - $\Box$  Ar/CF<sub>4</sub>/iC<sub>4</sub>H<sub>10</sub>=95/3/2
      - □ Same purity
  - Specific prototype parameters
    - Drift length: ~500mm
    - Active area: 200mm<sup>2</sup>
    - Integrated 266nm laser beam
    - MPGD detector as the readout
    - TPC cathode: -10kV
    - Readout Pads: 1280 channels





#### TPC prototype



Laser map in X-Y direction

Laser map along drift length

## **Electronics and DAQ**

- Amplifier and FEE
  - CASAGEM chip
  - □ 16Chs/chip
  - 4chips/Board
  - Gain: 20mV/fC
  - □ Shape time: 20ns

#### **DAQ**

- **• FPGA+ADC**
- 4 module/board
- 64Chs/module
- □ Sample: 40MHz
- **1280chs**



#### FEE Electronics and DAQ setup photos

## UV laser device

- **Gaussian laser device** 
  - Nd-LAG UV laser
  - □ Wave length: 266nm
  - Quantel Q-smart Lasers
  - **•** Frequency: 20Hz
  - □ Power: <20mJ/pulse
  - Trigger: BNC output



#### UV laser along the drift length



Parameters of the UV laser device

## Comparison of UV laser and <sup>55</sup>Fe



- Same test conditions under the same working gases and high voltage
- The ionization results indicate that the number for Ar:CO2(90:10)-gas and T2K-gas are similar for the ionization density.
- About the gas purity, the experiment shows all mixture gas of the purity of isobutane is 99.9% despite other gases are 99.999%.



All pads response and energy spectrum @laser and 55Fe



- □ The origin of the coordinate is set at the center of the endplate board.
- **X** and **Y** plan is set as the readout plane
- **Z** is set along the drift length from endplate to the cathode
- $\Box$  Z<sub>0</sub> plane is set at the first surface of the detector from cathode to endplate plane.
- The center of the pad is set as the pad's coordinate, and every pad has the specific x and y.

## Laser tracks reconstruction@T2K gas



- □ Same of working gas@T2K, same of high voltage, same of test conditions
- □ Different of GEMs@ 320V
- □ No any discharge to damage the detector
- Conclusion
  - All of the triple GEMs, double GEMs and GEM+Micromegas could be as the readout option for TPC prototype
  - 2000 of gain is fine to study UV laser
  - The spatial resolution and the drift velocity could be analyzed

## Space resolution



$$PRF(x, r, w) = \frac{\exp[-4\ln 2(1-r)x^2/w^2]}{1+4rx^2/w^2}$$



Left(drift length: 50mm) Right(drift length: 270mm)

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## Drift velocity measurement



- Two weeks of continuous testing (Data of  $E_{drift} = 220V/cm$  is still taking)
- **Room temperature recorded**
- Comparison of the drift velocity and the temperature
- Simulation of some influencing factors using Garfield/Gariflield++ software

Conclusion: 266nm UV laser can work well when it can be as the online monitor option.

## Summary

- Some motivations of TPC detector for the circular collider at high luminosity listed.
- Some update results of TPC module have been studies, it can effectively reduce ions at the low gain without the space charge and the discharge.
- 266nm UV laser beams system will be very useful in the TPC R&D for the future circular collider.
- The detector module will assembled and commissioned with the low power consumption ASIC chip in 2021.

## Thanks for your attention.